

	Type	L #	Hits	Search Text	DBs
1	BRS	L2	769	organic adj (TFT or (thin adj film adj transistor))	US- PGPUB; USPAT; EPO; JPO; DERWEN T
2	BRS	L7	897	(organic adj (TFT or (thin adj film adj transistor))) or OFET	US- PGPUB; USPAT; EPO; JPO; DERWEN T
3	BRS	L9	757	L7 not L8	US- PGPUB; USPAT; EPO; JPO; DERWEN T
4	BRS	L15	539	L7 not L10	US- PGPUB; USPAT; EPO; JPO
5	IS&R	L5	1	("6635508").PN.	USPAT; USOCR
6	IS&R	L11	1	("6635508").PN.	USPAT
7	BRS	L1	18	438/99.ccls. and 438/158.ccls.	US- PGPUB; USPAT; EPO; JPO; DERWEN T

	Type	L #	Hits	Search Text	DBs
8	IS&R	L6	3	("6724011").PN.	US- PGPUB; USPAT; USOCR; EPO; JPO; DERWEN T
9	BRS	L12	10	("20010029098"   "20020022299"   "20020155729"   "20020164835"   "5946551"   "6207472"   "6326640"   "6429457"   "6452207"   "6528816").PN.	US- PGPUB; USPAT; USOCR
10	BRS	L13	50	(organic near15 cavity) and TFT	US- PGPUB; USPAT; EPO; JPO; DERWEN T
11	BRS	L3	290	(organic adj (TFT or (thin adj film adj transistor))) and (spin adj coat\$)	US- PGPUB; USPAT; EPO; JPO; DERWEN T
12	BRS	L4	479	(organic adj (TFT or (thin adj film adj transistor))) not ((organic adj (TFT or (thin adj film adj transistor))) and (spin adj coat\$))	US- PGPUB; USPAT; EPO; JPO; DERWEN T
13	BRS	L16	458	L7 not L10	US- PGPUB; USPAT; EPO

	Type	L #	Hits	Search Text	DBs
14	BRS	L10	591	L8 and (transistor or FET or MOSFET or OFET)	US- PGPUB; USPAT; EPO; JPO; DERWEN T
15	BRS	L14	758	L7 not L10	US- PGPUB; USPAT; EPO; JPO; DERWEN T
16	BRS	L8	1520	257/40.ccls.	US- PGPUB; USPAT; EPO; JPO; DERWEN T